

Lattice Thermal Properties

- Planck distribution
- Average thermal energy
- Density of states (DOS)
- Phase-space summation
- Debye model
- Anharmonicity
- Thermal conductivity

HW assignment: Ch. 8, p.5

Concept of Phonons

★ Phonons: quantization of lattice vibration

1. Energy of a vibrational mode (normal mode) with frequency ω is $E = (n + 1/2)\hbar\omega$, which corresponds to the creation of n quanta(phonons). The ground state ($n = 0$, or zero phonon) has an energy $\frac{1}{2}\hbar\omega$ (zero-point motion).
2. Phonon is particle-like, and it has a momentum $\hbar\mathbf{k}$ (k restricted in the 1st Brillouin zone) Because \mathbf{k} and $\mathbf{k}' = \mathbf{k} + \mathbf{G}$ are equivalent, we call the momentum the "crystal momentum".
3. Phonons are bosons, so more than one phonon can occupy the same mode.

Average occupancy:

$$n(\hbar\omega) = \frac{1}{e^{\frac{\hbar\omega}{k_B T}} - 1}$$

Planck distribution

Average occupancy of a state for bosons (phonons or photons) which behave like harmonic oscillators: In a given normal mode, the frequency is ω and the energy of an n -particle state is $(n + 1/2)\hbar\omega$. If the system is in thermal contact with a reservoir with temperature T , then the relative probability of finding the system in a given state $[E_n = (n + 1/2)\hbar\omega]$ is proportional to the Boltzmann factor

$$p_n \sim e^{-E_n/k_B T} = e^{-E_n/\tau}; \quad \tau \equiv k_B T.$$

The thermal average of any physical quantity that depends on E_n is given by

$$\langle A \rangle = \sum_n p_n A(E_n) / \sum_n P_n = \sum_n e^{-E_n/\tau} A(E_n) / \sum_n e^{-E_n/\tau}.$$

$$\text{Let } A = n \Rightarrow \text{Average occupancy } \langle n \rangle = \sum_{n=0}^{\infty} e^{-\hbar\omega(n+1/2)/\tau} n / \sum_n e^{-\hbar\omega(n+1/2)/\tau}$$

$$= \sum_{n=0}^{\infty} x^n n / \sum_n x^n; \quad (x = e^{-\hbar\omega/\tau} < 1)$$

$$\text{Let } f(x) = \sum_{n=0}^{\infty} x^n = \frac{1}{1-x} \Rightarrow \frac{\partial f(x)}{\partial x} = \sum_{n=0}^{\infty} n x^{n-1} = \frac{1}{(1-x)^2}$$

$$\Rightarrow \sum_{n=0}^{\infty} n x^n = x \frac{\partial f}{\partial x} = \frac{x}{(1-x)^2}$$

$$\text{or } \langle n \rangle = \frac{x}{(1-x)^2} / (1-x)^{-1} = \frac{x}{1-x} = \frac{1}{x^{-1} - 1} = \frac{1}{e^{\hbar\omega/\tau} - 1}$$

Average thermal energy in a given mode

$$U_\lambda = \langle E_\lambda \rangle = \sum_n e^{-E_n/\tau} (n\hbar\omega_\lambda) / \sum_n e^{-E_n/\tau} = \hbar\omega_\lambda \langle n \rangle_\lambda = \frac{\hbar\omega_\lambda}{e^{\hbar\omega_\lambda/\tau} - 1}.$$

\Rightarrow Total thermal energy of the lattice is

$$U = \sum_\lambda U_\lambda = \sum_\lambda \frac{\hbar\omega_\lambda}{e^{\hbar\omega_\lambda/\tau} - 1} = \int D(\omega) \frac{\hbar\omega}{e^{\hbar\omega/\tau} - 1} d\omega,$$

where

$$D(\omega) = \sum_\lambda \delta(\omega - \omega_\lambda) = \sum_{\mathbf{k}, p} \delta(\omega - \omega_p(\mathbf{k})) = \sum_p D_p(\omega)$$

is called the density of states (DOS) and

$$D_p(\omega) = \sum_{\mathbf{k}} \delta(\omega - \omega_p(\mathbf{k}))$$

is the DOS of branch p .

$$\text{Note: } \int D(\omega) d\omega = \sum_\lambda \int \delta(\omega - \omega_\lambda) d\omega = \sum_\lambda 1 = N_m$$

= total number of phonon modes in the crystal

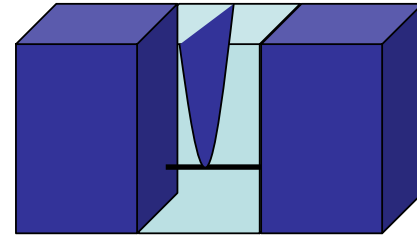
= (dimensionality). (number of atoms in crystal) = total number of degrees of freedom.

Density of states for various dimensions

$$N_d(E) \rightarrow N_3(E) \propto \sqrt{E}, \quad N_2(E) \propto \theta(E), \quad N_1(E) = 1/\sqrt{E}$$

- Density of states (DOS) = #states per unit energy

$$\sum_{\vec{k}} = \left(\frac{L}{2\pi}\right)^d \int dk^d$$



In 2D:

$$\left(\frac{L}{2\pi}\right)^2 \int dk^2 = \int dE \quad N(E) \quad \text{DOS}$$

$$E = \frac{\hbar^2 k^2}{2m^*} \longrightarrow dE = \frac{\hbar^2 2k dk}{2m^*} \longrightarrow \left(\frac{L}{2\pi}\right)^2 \int dk^2 = \int dE \quad \left(\frac{L}{2\pi}\right)^2 \frac{2m^*}{\hbar^2}$$

DOS, $N(E) = \text{constant}$



Phonon bottleneck in QD

- In polar semiconductor
- Quantum dots with discrete states



Meaning of the phase-space summation

$$(\sum_{\mathbf{k}} = v \int \frac{d^3 k}{(2\pi)^3} = V \int \frac{d^3 p}{h^3})$$

1-D case: (a linear chain of N atoms with length L). The wave function $\psi(x)$ must vanish at the boundaries ($x = 0$ and $x = L$) if both ends are fixed $\Rightarrow \psi(x) = \sin(k_n x)$ with $k_n L = n\pi$ or $k_n = \frac{n\pi}{L}$, $n = 1, 2, \dots, N-1$. So k_n takes on discrete values spaced by (π/L) and restricted within $(0, \frac{n\pi}{L}) = (0, \frac{\pi}{a})$. If we choose the origin ($x = 0$) at the mid point of the chain, then the boundary conditions become

$$\psi(x = -L/2) = \psi(x = L/2) = 0$$

and we have

$$\psi(x) \sim \begin{cases} \cos(k_n x); k_n = n\pi/(L/2) \\ \sin(\bar{k}_n x); \bar{k}_n = (2n+1)\pi/(L/2) \end{cases}$$

The spacing of quantified values of k_n (or \bar{k}_n) becomes $(\frac{2\pi}{L})$ and restricted within $(0, \frac{\pi}{a})$

For large values of L , we can ignore the difference of k_n and \bar{k}_n and choose linear combinations of $\cos(k_n x)$ and $\sin(k_n x)$ to form $e^{ik_n x}$ and $e^{-ik_n x}$. Now, k_n takes on discrete values spaced by $\frac{2\pi}{L}$ and restricted within $(-\frac{\pi}{a}, \frac{\pi}{a})$ if we use $e^{ik_n x}$ and allow k_n to be both positive and negative.

Periodic boundary condition (PBC)

Alternatively, we can replace the boundary conditions (that both ends be fixed) by the periodic boundary condition that requires $\psi(x) = \psi(x + L)$. The difference between these two types of BCs is negligible when L is large enough. The solution to PBC is $\psi(x) \sim e^{ik_n x}$ with $k_n L = n2\pi$ or $k_n = n(\frac{2\pi}{L})$ restricted within the 1st Brillouin zone $(-\frac{\pi}{a}, \frac{\pi}{a}]$. The number of allowed k_n values is exactly N .

The phase space sum, $\sum_{\mathbf{k}}$ means that we sum over allowed values of $k_n = n(\frac{2\pi}{L})$

$$\text{So, } \sum_{\mathbf{k}} = \sum_n \sim \int_{BZ} \frac{dk}{(2\pi/L)} = L \int_{BZ} \frac{dk}{(2\pi)}.$$

Generalized to 3D, we have

$$\sum_{\mathbf{k}} = \sum_{n_1, n_2, n_3} \int_{BZ} \frac{d^3 k}{(2\pi/L)^3} = V \int_{BZ} \frac{d^3 k}{(2\pi)^3}$$

$$D(\omega) = \sum_{\mathbf{k}} \delta(\omega - \omega(\mathbf{k})) = V \int \frac{d^3 k}{(2\pi)^3} \delta(\omega - \omega(k))$$

$$\Rightarrow \int D(\omega) d\omega = V \int_{BZ} \frac{d^3 k}{(2\pi)^3} = V \frac{\Omega_k}{(2\pi)^3} = \frac{V}{V_c} = N,$$

where Ω_k = volume of unit cell in reciprocal space = $(2\pi)^3/V_c$ volume of unit cell in real space.

Evaluation of DOS

Once $\omega(\mathbf{k})$ versus \mathbf{k} is known, DOS can be evaluated in two ways:

(i) Direct method:

$$D(\omega) = V \int \frac{dS_\omega}{(2\pi)^3} \frac{1}{|d\omega/dk|}; S(\omega) = \text{constant } \omega \text{ surface}$$

(ii) Indirect method: $D(\omega) = dN(\omega)/d\omega$, where $N(\omega) = V \int \frac{d^3k}{(2\pi)^3} \Theta(\omega - \omega(k))$.

★ Debye model:

$\omega = v|k|$ with $|k|$ restricted in $(0, k_D)$, k_D is chosen such that $\int D(\omega)d\omega = 3N$.

$$\begin{aligned} D(\omega) &= \sum_{\lambda} \delta(\omega - \omega_{\lambda}) = 3 \sum_{\mathbf{k}} \delta(\omega - v|\mathbf{k}|) = \frac{3V}{(2\pi)^3} \int_0^{k_D} d^3k \delta(\omega - vk) \\ &= \frac{3V}{(2\pi)^3} \int_0^{k_D} 4\pi k^2 dk \delta(\omega - vk) = \frac{3V}{(2\pi)^3} \int_0^{k_D} 4\pi k^2 \frac{1}{v} \delta(k - k')|_{k'=\omega/v} \\ &= \frac{3V}{(2\pi)^3} \frac{4\pi}{v} \left(\frac{\omega}{v}\right)^2 \Theta(k_D - k') = \frac{3V}{2\pi^2 v^3} \omega^2 \Theta(\omega_D - \omega). \end{aligned}$$

Alternatively, use

$$\begin{aligned} N(\omega) &= \sum_{\lambda} \Theta(\omega - \omega_{\lambda}) = 3 \sum_{\mathbf{k}} \Theta(\omega - vk) = \frac{3V}{(2\pi)^3} \int_0^{k_D} d^3k \Theta(\omega - vk) \\ &= \frac{3V}{(2\pi)^3} \int_0^{k_D} 4\pi k^2 dk \Theta(\omega/v - k) = \frac{3V}{(2\pi)^3} \int_0^{\omega/v} 4\pi k^2 dk \text{ (if } \omega/v < k_D) = \frac{3V}{(2\pi)^3} \frac{4\pi}{3} (\omega/v)^3. \end{aligned}$$

$$D(\omega) = \frac{dN(\omega)}{d\omega} = \frac{3V}{2\pi^2 v^3} \omega^2, \quad \text{if } \omega/v < k_D \equiv \omega_D/v.$$

To determine ω_D , we use

$$\int_0^{\omega_D} D(\omega) d\omega = 3N = \frac{3V}{2\pi^2 v^3} \int_0^{\omega_D} \omega^2 d\omega = \frac{V}{2\pi^2 v^3} \omega_D^3 = \frac{V}{2\pi^2} k_D^3$$

$$\Rightarrow k_D = (\omega_D/v) = (6\pi^2 N/V)^{1/3} \Rightarrow D(\omega) = \frac{9N}{\omega_D^3} \omega^2.$$

Lattice thermal energy in Debye model

$$\begin{aligned} U \int D(\omega) \frac{\hbar\omega}{e^{\hbar\omega/\tau} - 1} d\omega &= \frac{9N\hbar}{\omega_D^3} \int_0^{\omega_D} \frac{\omega^3}{e^{\hbar\omega/\tau} - 1} d\omega \\ &= \frac{9N\tau^4}{\omega_D^3 \hbar^3} \int_0^{x_D} \frac{x^3}{e^x - 1} dx = \frac{9Nk_B T^4}{\Theta^3} \int_0^{x_D} \frac{x^3}{e^x - 1} dx, \end{aligned}$$

$\Theta = \hbar\omega_D/k_B = \frac{\hbar v}{k_B} (6\pi^2 N/V)^{1/3}$ is called "Debye temperature".

$$\int_0^{x_D} \frac{x^3}{e^x - 1} dx \approx \begin{cases} \int_0^\infty \frac{x^3}{e^x - 1} dx = \frac{\pi^4}{15} \text{ as } T \rightarrow 0 \\ \int_0^{x_D} x^2 dx = \frac{1}{3}x_D^3 \text{ as } x = \hbar\omega/T \rightarrow 0 \text{ (high T limit)} \end{cases}$$

$$\Rightarrow U(T) = \begin{cases} \frac{3}{5}\pi^4 Nk_B T^4 / \Theta^3 \text{ as } T \rightarrow 0 \\ 3Nk_B T \text{ as } T \rightarrow \infty \end{cases}$$

★ Heat capacity

$$C_V = \frac{\partial U}{\partial T} = \begin{cases} \frac{12\pi^4}{5} Nk_B T^3 / \Theta^3 \text{ as } T \rightarrow 0 \\ 3Nk_B \text{ as } T \rightarrow \infty \end{cases}$$

★ Einstein model:

$$D(\omega) = 3N\delta(\omega - \omega_0) \text{ (appropriate for optical phonons)}$$

$$U = 3N\hbar\omega_0/(e^{\hbar\omega_0/\tau} - 1)$$

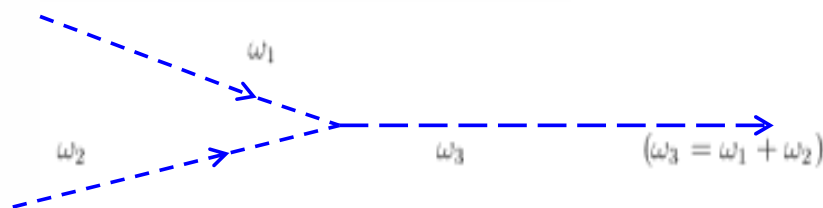
$$C_V = \frac{\partial U}{\partial T} = 3Nk_B \left(\frac{\hbar\omega_0}{\tau}\right)^2 \frac{e^{\hbar\omega_0/\tau}}{(e^{\hbar\omega_0/\tau} - 1)^2} \rightarrow \begin{cases} 3Nk_B (\hbar\omega_0/\tau)^2 e^{-\hbar\omega_0/\tau} \text{ as } T \rightarrow 0 \\ 3Nk_B \text{ as } T \rightarrow \infty \end{cases}$$

★ Anharmonicity:

Consequence of harmonic theory:

1. No phonon-phonon interaction
2. No thermal expansion
3. No pressure/temperature dependence in elastic constants
4. $C_v \rightarrow 3Nk_B$ as $T \gg \Theta$.

Evidence of anharmonicity: sum frequency generation



Thermal Expansion (1D model)

$$U(x) = cx^2 - gx^3 + O(x^4)$$

$$\langle x \rangle = \int dx e^{-\beta U(x)} x / \int dx e^{-\beta U(x)}; \beta = 1/\tau$$

$$= \int dx e^{-\beta cx^2} x (e^{\beta gx^3}) / \int dx e^{-(\beta cx^2 - \beta gx^3)}$$

$$\sim \int dx e^{-\beta cx^2} x (1 + \beta gx^3) / \int dx e^{-\alpha x^2} I(\alpha) = \int dx e^{-\alpha x^2} = \left(\frac{\pi}{\alpha}\right)^{1/2}; \alpha = \beta c$$

$$\left(\frac{\partial}{\partial \alpha}\right)^2 I(\alpha) = \int x^4 e^{-\alpha x^2} dx = \frac{1}{2} \frac{3}{2} \left(\frac{\pi}{\alpha}\right)^{1/2} \alpha^{-2}$$

$$\Rightarrow \langle x \rangle = (\alpha g / c) \cdot \frac{3}{4} \alpha^{-2} = \frac{3}{4} \frac{g}{c \alpha} = \frac{3g}{4c^2} k_B T$$

$$\Rightarrow \text{Thermal expansion coef.} = \left(\frac{3g}{4c^2}\right) k_B.$$

Thermal conductivity

$\mathbf{J}_u = -K \Delta T$, where ΔT is the temperature gradient.

\mathbf{J}_u = flux of thermal energy

$$\mathbf{J}_A = \text{flux of } (A) = \frac{\Delta A}{\Delta t} / \text{unit area} = \rho_A \cdot \mathbf{v}.$$

Thermal energy density gained due particle flow between t and $t + \tau$.

$$u = -nc\Delta T = -C\Delta T, \quad C = \text{heat capacity/volume} = -C\left(\frac{dT}{dx}\right)v_x\tau.$$

$v_x\tau$ = distance travelled within time τ . τ = mean free time.

$$J_u = \langle ncx \rangle = -c\left(\frac{dT}{dx}\right) \langle v_x^2 \rangle \tau = -\frac{1}{3}c \langle v^2 \rangle \tau \left(\frac{dT}{dx}\right) = -\frac{1}{3}Cvl\left(\frac{dT}{dx}\right),$$

where $v = \sqrt{\langle v^2 \rangle}$ = average particle velocity, $l = v\tau$ = mean free path

$$\Rightarrow K = \frac{1}{3}Cvl \quad \dots \text{ valid for both phonons and electrons.}$$

Phonon mean free path is determined by phonon-defect scattering or phonon-phonon scattering.

$$l^{-1} \propto \text{scattering rate} \propto \text{number of phonons available}$$

$$\langle n \rangle = (e^{\hbar\omega/k_B T} - 1)^{-1} = k_B T / \hbar\omega \quad \text{for } k_B T \ll \hbar\omega.$$

So, at high temperature ($k_B T \ll \hbar\omega$) number of phonons $\propto T$ and $l \propto 1/T$ due to phonon-phonon scattering.

Note: Any momentum-conserving scattering ($\mathbf{k}_1 + \mathbf{k}_2 = \mathbf{k}_3$) (N-process) will lead to no change in thermal current. Only the Umklapp process (U-process), in which $\mathbf{k}_1 + \mathbf{k}_2 = \mathbf{k}_3 + \mathbf{G}$, \mathbf{G} = a nonzero reciprocal lattice vector, can change the thermal current and establish thermal equilibrium.

★ Geometric effect (phonon-scattering due to boundaries)

l is limited by the width of the sample (D). When phonon-phonon scattering becomes negligible at the low temperatures, the geometric effect prevails, and we have $K \sim CvD$. Thus,

$$K \sim \begin{cases} T^3 & \text{as } T \rightarrow 0 \\ T^{-1} & \text{as } T \ll \Theta \end{cases}$$